

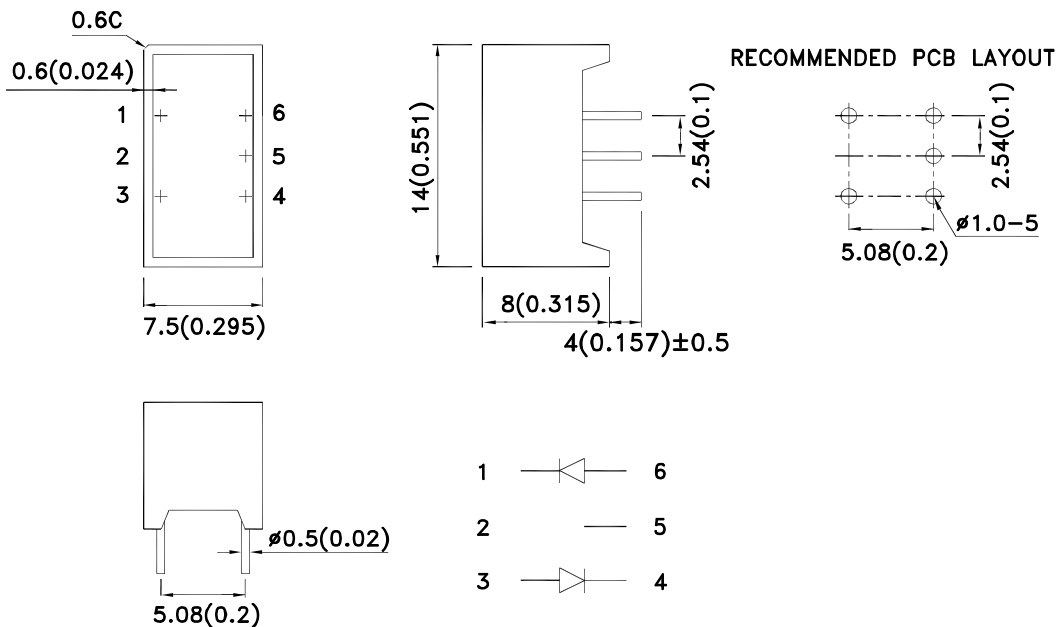
### Features

- Uniform light emitting area.
- Easily mounted on P.C. boards or industry standard sockets.
- Flush mountable.
- Excellent on/off contrast.
- Can be used with panels and legend mounts.
- Mechanically rugged
- RoHS compliant.

### Description

The Super Bright Yellow device is made with AlGaInP (on GaAs substrate) light emitting diode chip.

### Package Dimensions & Internal Circuit Diagram



**Notes:**

1. All dimensions are in millimeters (inches). Tolerance is  $\pm 0.25(0.01)$  unless otherwise noted.
2. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.



## Selection Guide

| Part No. | Dice                          | Lens Type       | Iv (mcd) [1]<br>@ 20mA |      |
|----------|-------------------------------|-----------------|------------------------|------|
|          |                               |                 | Min.                   | Typ. |
| DE/2SYKD | Super Bright Yellow (AlGaInP) | YELLOW DIFFUSED | 700                    | 1100 |

Note:

- Luminous intensity/ luminous Flux: +/-15%.

## Electrical / Optical Characteristics at TA=25°C

| Symbol                | Parameter                | Device              | Typ. | Max. | Units | Test Conditions           |
|-----------------------|--------------------------|---------------------|------|------|-------|---------------------------|
| $\lambda_{peak}$      | Peak Wavelength          | Super Bright Yellow | 590  |      | nm    | I <sub>F</sub> =20mA      |
| $\lambda_D$ [1]       | Dominant Wavelength      | Super Bright Yellow | 590  |      | nm    | I <sub>F</sub> =20mA      |
| $\Delta\lambda_{1/2}$ | Spectral Line Half-width | Super Bright Yellow | 20   |      | nm    | I <sub>F</sub> =20mA      |
| C                     | Capacitance              | Super Bright Yellow | 20   |      | pF    | V <sub>F</sub> =0V;f=1MHz |
| V <sub>F</sub> [2]    | Forward Voltage          | Super Bright Yellow | 2.0  | 2.5  | V     | I <sub>F</sub> =20mA      |
| I <sub>R</sub>        | Reverse Current          | Super Bright Yellow |      | 10   | uA    | V <sub>R</sub> =5V        |

Notes:

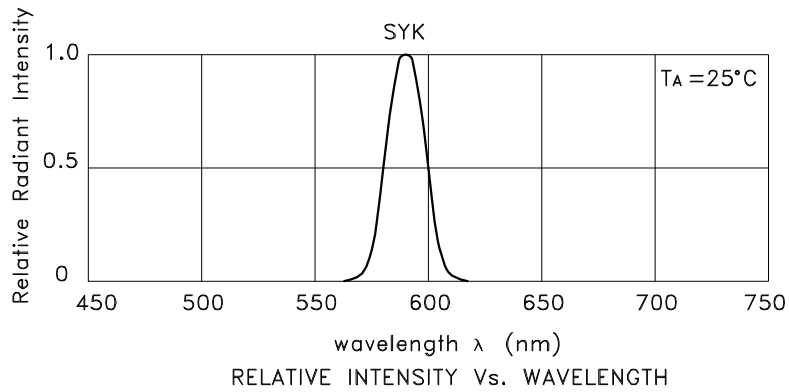
- Wavelength: +/-1nm.
- Forward Voltage: +/-0.1V.

## Absolute Maximum Ratings at TA=25°C

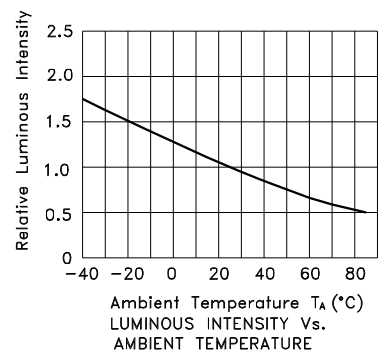
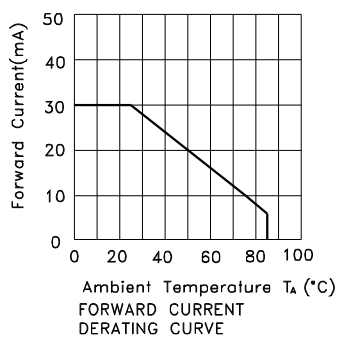
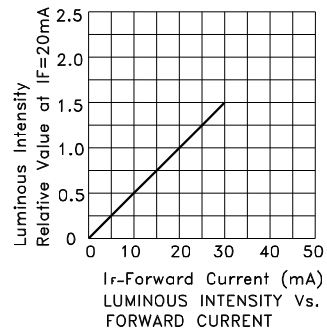
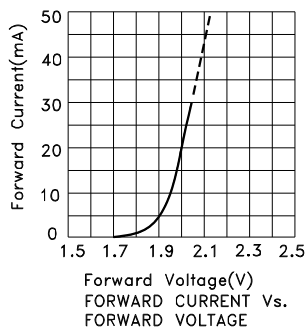
| Parameter                       | Super Bright Yellow   | Units |
|---------------------------------|-----------------------|-------|
| Power dissipation               | 75                    | mW    |
| DC Forward Current              | 30                    | mA    |
| Peak Forward Current [1]        | 175                   | mA    |
| Reverse Voltage                 | 5                     | V     |
| Operating / Storage Temperature | -40°C To +85°C        |       |
| Lead Solder Temperature[2]      | 260°C For 3-5 Seconds |       |

Notes:

- 1/10 Duty Cycle, 0.1ms Pulse Width.
- 2mm below package base.

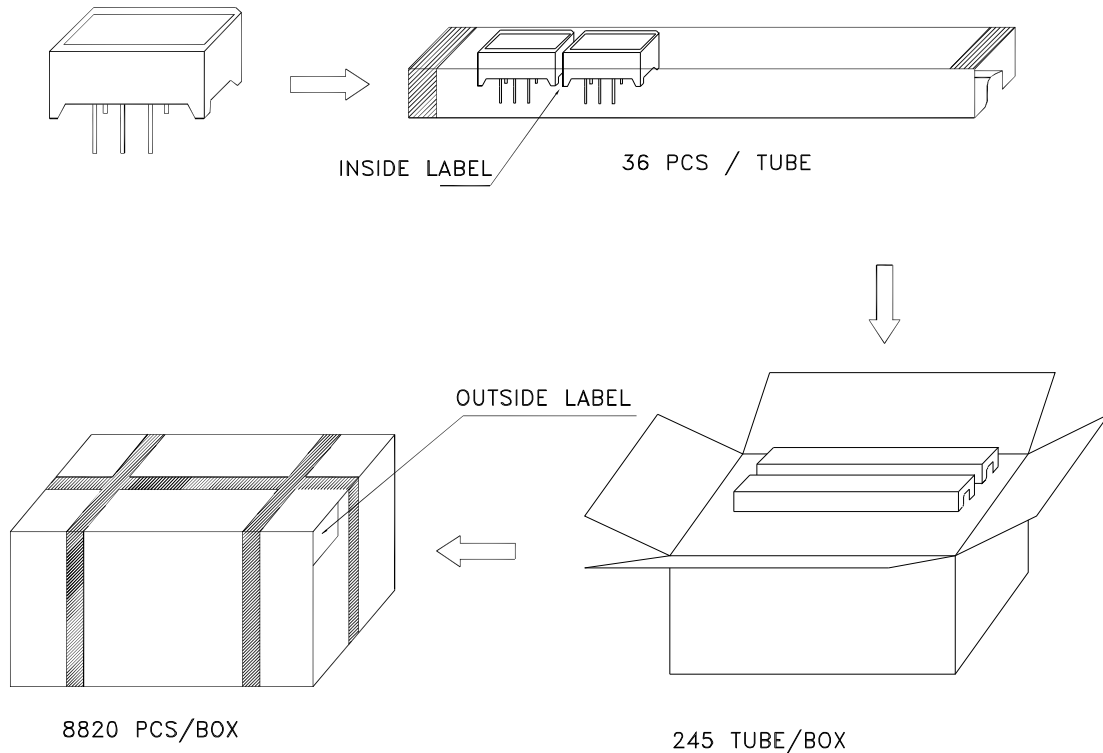


**Super Bright Yellow DE/2SYKD**

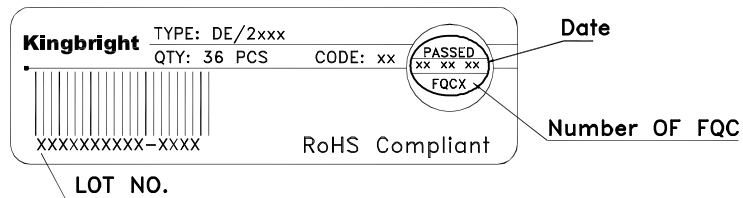


**PACKING & LABEL SPECIFICATIONS**

**DE/2SYKD**



**Inside Label On IC-tube**



**Outside Label On Box**

